



RS07A THRU RS07M

SURFACE MOUNT FAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 0.7 Ampere

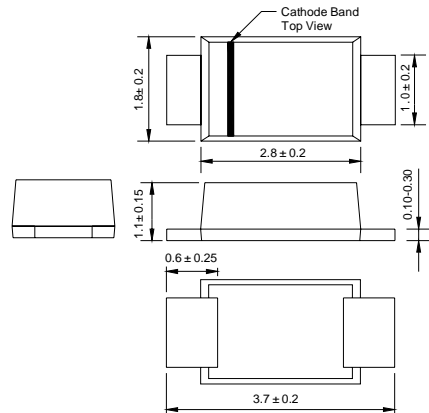
FEATURES

Glass passivated device
 Ideal for surface mounted applications
 Low reverse leakage
 Metallurgically bonded construction
 High temperature soldering guaranteed:
 260°C/10 seconds, 0.375" (9.5mm) lead length,
 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC SOD-123FL molded plastic body over passivated chip
Terminals: Solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.0007 ounce, 0.02 grams

SOD-123FL



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	RS07A	RS07B	RS07D	RS07G	RS07J	RS07K	RS07M	UNITS
		RA	RB	RD	RG	RJ	RK	RM	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_A=100^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	0.7							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) $T_L=25^\circ\text{C}$	I_{FSM}	25.0							Amps
Maximum instantaneous forward voltage at 0.7A	V_F	1.30							Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	I_R	5.0 100.0							μA
Maximum reverse recovery time (NOTE 2)	t_{rr}	150				250	500		ns
Typical junction capacitance (NOTE 3)	C_J	4							pF
Typical thermal resistance (NOTE 4)	$R_{\theta JA}$	180							K/W
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +150							$^\circ\text{C}$

- Note:**
1. Averaged over any 20ms period.
 2. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.
 3. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 4. Thermal resistance junction to ambient, 6.0 mm² copper pads to each terminal.

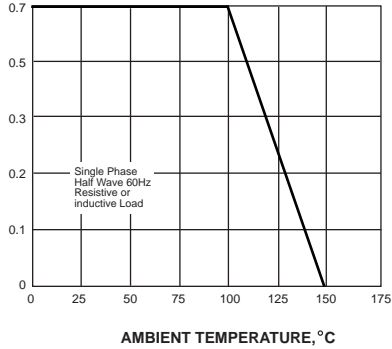


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RATINGS AND CHARACTERISTIC CURVES RS07A THRU RS07M

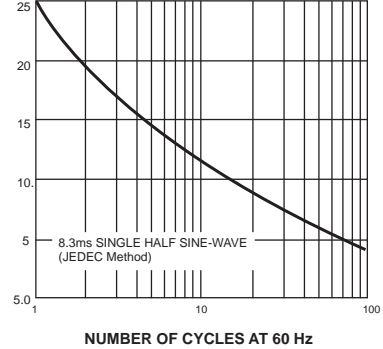
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



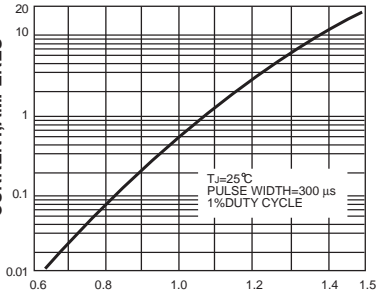
PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



INSTANTANEOUS FORWARD CURRENT,AMPERES

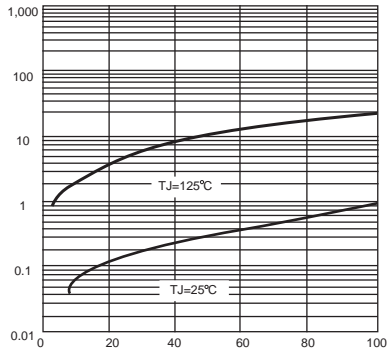
FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE,
VOLTS

INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES

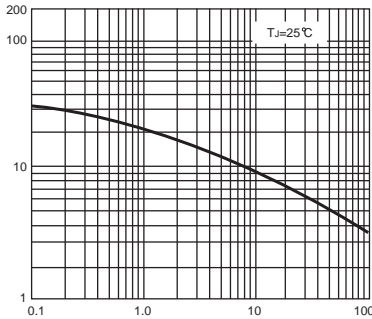
FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE, %

JUNCTION CAPACITANCE, pF

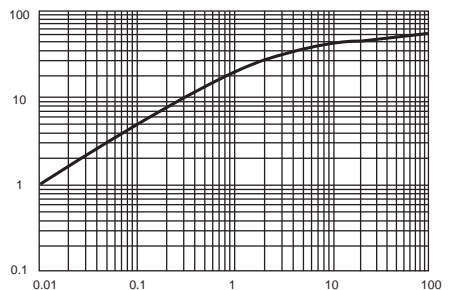
FIG. 5-TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



t, PULSE DURATION, sec.

单击下面可查看定价，库存，交付和生命周期等信息

[>>ZG\(中鑫半导体\)](#)